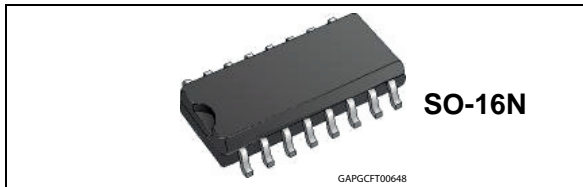


## Automotive fully integrated H-bridge motor driver

Datasheet - preliminary data



### Features

Type	$R_{DS(on)}$	$I_{out}$	$V_{CCmax}$
VNH7070AS-E	70 m $\Omega$ typ (per leg)	15 A	41 V

- Automotive qualified
- Output current: 15 A
- 3 V CMOS-compatible inputs
- Undervoltage shutdown
- Overvoltage clamp
- Thermal shutdown
- Cross-conduction protection
- Current and power limitation
- Very low standby power consumption
- Protection against loss of ground and loss of  $V_{CC}$
- PWM operation up to 20 KHz
- CS diagnostic functions
  - Analog motor current feedback
  - Output short to ground detection
  - Thermal shutdown indication
  - OFF-state open-load detection
  - Output short to  $V_{CC}$  detection
- Output protected against short to ground and short to  $V_{CC}$
- Standby Mode
- Half Bridge Operation
- Package: ECOPACK<sup>®</sup>

### Description

The VNH7070AS-E is a full bridge motor driver intended for a wide range of automotive applications. The device incorporates a dual monolithic high-side driver and two low-side switches.

Both switches are designed using STMicroelectronics' well known and proven proprietary VIPower<sup>®</sup> M0 technology that allows to efficiently integrate on the same die a true Power MOSFET with an intelligent signal/protection circuitry. The three dies are assembled in SO-16N package on electrically isolated leadframes.

Moreover, its fully symmetrical mechanical design allows superior manufacturability at board level. The input signals  $IN_A$  and  $IN_B$  can directly interface to the microcontroller to select the motor direction and the brake condition. A SEL0 pin is available to address to the microcontroller the information available on the CS. The CS pin allows to monitor the motor current by delivering a current proportional to the motor current value. The normal operating condition is explained in the truth table.

The PWM, up to 20 KHz, allows to control the speed of the motor in all possible conditions. In all cases, a low level state on the PWM pin turns off both the  $LS_A$  and  $LS_B$  switches.

**Table 1. Device summary**

Package	Order codes	
	Tube	Tape and reel
SO-16N	VNH7070AS-E	VNH7070ASTR-E

# Contents

- 1      Block diagram and pin description ..... 5**
  
- 2      Electrical specifications ..... 7**
  - 2.1    Absolute maximum ratings ..... 7
  - 2.2    Thermal data ..... 8
  - 2.3    Electrical characteristics ..... 9
  
- 3      Application information ..... 18**
  - 3.1    GND protection network against reverse battery ..... 18
    - 3.1.1    Diode (DGND) in the ground line ..... 18
  - 3.2    Immunity against transient electrical disturbances ..... 18
  
- 4      Package and packing information ..... 20**
  - 4.1    ECOPACK® ..... 20
  - 4.2    SO-16N mechanical data ..... 20
  
- 5      Revision history ..... 22**

## List of tables

Table 1.	Device summary . . . . .	1
Table 2.	Block description . . . . .	5
Table 3.	Pin definitions and functions . . . . .	6
Table 4.	Absolute maximum ratings . . . . .	7
Table 5.	Thermal data . . . . .	8
Table 6.	Power section . . . . .	9
Table 7.	Logic inputs (IN <sub>A</sub> , IN <sub>B</sub> ) (V <sub>CC</sub> = 7 V up to 28 V; -40 °C < T <sub>j</sub> < 150 °C) . . . . .	9
Table 8.	Switching (V <sub>CC</sub> = 13 V, R <sub>LOAD</sub> = 3.7 Ω) . . . . .	10
Table 9.	Protections and diagnostics (V <sub>CC</sub> = 7 V up to 18 V; -40 °C < T <sub>j</sub> < 150 °C) . . . . .	11
Table 10.	CS (7 V < V <sub>CC</sub> < 18 V) . . . . .	12
Table 11.	Operative condition - truth table . . . . .	16
Table 12.	On-state fault conditions- truth table Fault on leg A (preliminary) . . . . .	16
Table 13.	Off-state -truth table . . . . .	17
Table 14.	ISO 7637-2 - electrical transient conduction along supply line . . . . .	19
Table 15.	SO-16N mechanical data . . . . .	21
Table 16.	Document revision history . . . . .	22

## List of figures

Figure 1.	Block diagram . . . . .	5
Figure 2.	Configuration diagram (top view) . . . . .	6
Figure 3.	Current and voltage conventions . . . . .	7
Figure 4.	$T_{DSTKON}$ . . . . .	13
Figure 5.	Definition of the low-side switching times . . . . .	14
Figure 6.	Definition of the high-side switching times . . . . .	14
Figure 7.	Low-side turn-on delay time . . . . .	15
Figure 8.	Time to shutdown for the low-side driver . . . . .	15
Figure 9.	SO-16N package dimensions . . . . .	20

# 1 Block diagram and pin description

Figure 1. Block diagram

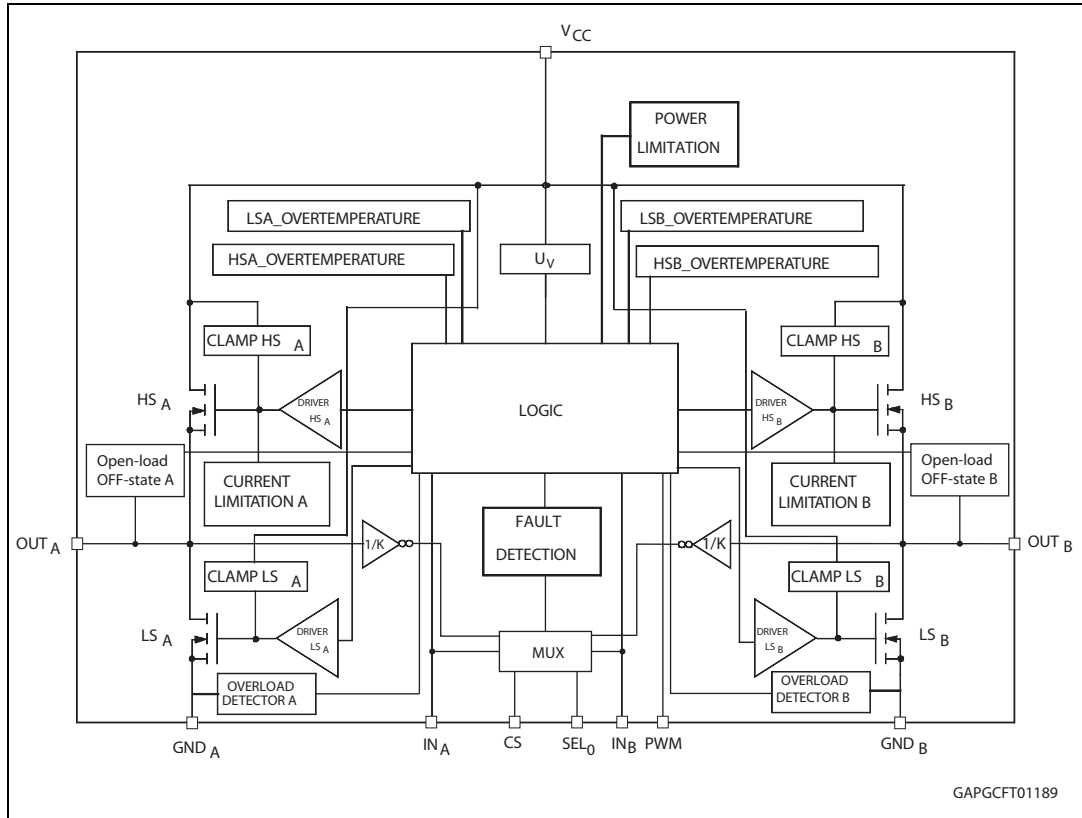


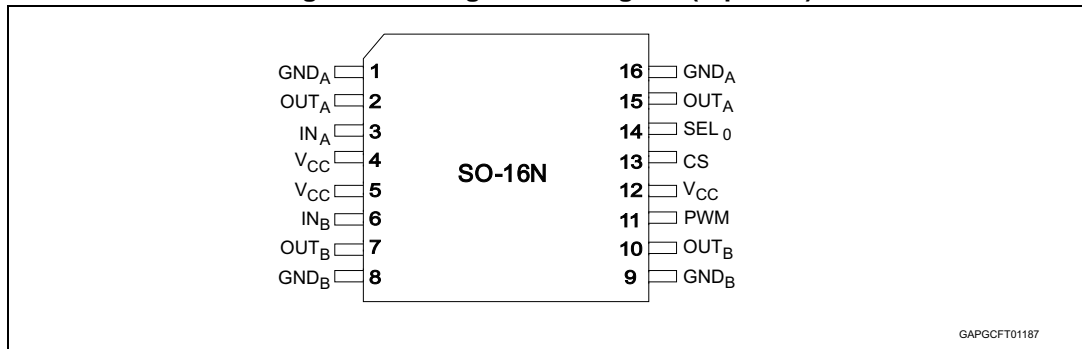
Table 2. Block description

Name	Description
Logic control	Allows the turn-on and the turn-off of the high-side and the low-side switches according to the truth table.
Undervoltage	Shuts down the device for battery voltage lower than 4 V.
High-side and low-side clamp voltage	Protect the high-side and the low-side switches from the high voltage on the battery line.
High-side and low-side driver	Drive the gate of the concerned switch to allow a proper $R_{on}$ for the leg of the bridge.
Current limitation	Limits the motor current in case of short circuit.
High-side and low-side overtemperature protection	In case of short-circuit with the increase of the junction temperature, it shuts down the concerned driver to prevent degradation and to protect the die.
Low-side overload detector	Detects when low side current exceeds shutdown current and latches off the concerned Low side.

**Table 2. Block description (continued)**

Name	Description
Fault detection	Signalizes the abnormal behavior of the switch through CS pin.
Power limitation	Limits the power dissipation of the high-side driver inside safe range in case of short to ground condition.

**Figure 2. Configuration diagram (top view)**

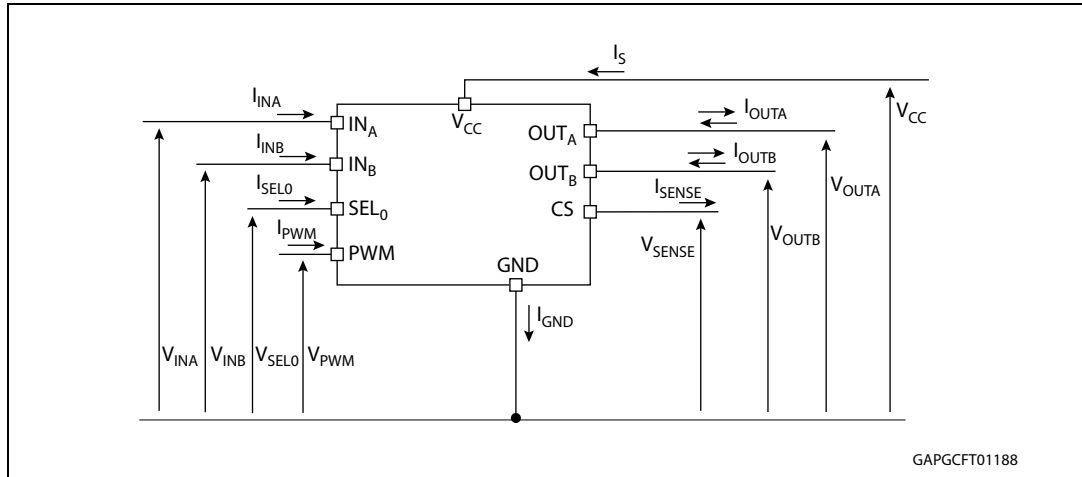


**Table 3. Pin definitions and functions**

Pin N°	Symbol	Function
1, 16	GND <sub>A</sub>	Source of low-side switch A
2, 15	OUT <sub>A</sub>	Source of high-side switch A / drain of low-side switch A
3	IN <sub>A</sub>	Clockwise input
4, 5, 12	V <sub>CC</sub>	Power supply voltage
6	IN <sub>B</sub>	Counter clockwise input
7, 10	OUT <sub>B</sub>	Source of high-side switch B / drain of low-side switch B
8, 9	GND <sub>B</sub>	Source of low-side switch B
11	PWM	Voltage controlled input pin with hysteresis, CMOS compatible. Gates of low-side FETS get modulated by the PWM signal during their on phase allowing speed control of the motor
13	CS	Multiplexed analog sense output pin; it delivers a current proportional to the motor current according to the leg selection.
14	SEL <sub>0</sub>	Active high compatible with 3 V and 5 V CMOS outputs pin; n combination with IN <sub>A</sub> , IN <sub>B</sub> , it addresses the CS information delivered to the micro.

## 2 Electrical specifications

Figure 3. Current and voltage conventions



GAPGCFT01188

### 2.1 Absolute maximum ratings

Stressing the device above the rating listed in [Table 4: Absolute maximum ratings](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	38	V
$-V_{CC}$	Reverse DC Supply Voltage	0.3	V
$I_{max}$	Maximum output current (continuous)	Internally limited	A
$I_R$	Reverse output current (continuous)	-15	A
$V_{CCPK}$	Maximum transient supply voltage (ISO 16750-2:2010 Test B clamped to 40 V; $R_L = 4 \Omega$ )	40	V
$V_{CCJS}$	Maximum jump start voltage for single pulse short circuit protection	28	V
$I_{IN}$	Input current ( $IN_A$ and $IN_B$ pins)	-1 to 10	mA
$I_{SELO}$	$SEL_0$ DC input current	-1 to 10	mA
$I_{PWM}$	PWM input current	-1 to 10	mA
$-I_{GND}$	DC reverse ground pin current	200	mA
$I_{SENSE}$	CS pin DC output current ( $V_{GND} = V_{CC}$ and $V_{SENSE} < 0 V$ )	10	mA
	CS pin DC output current in reverse ( $V_{CC} < 0 V$ )	-20	

Table 4. Absolute maximum ratings (continued)

Symbol	Parameter	Value	Unit
V <sub>ESD</sub>	Electrostatic discharge (Human body model: R = 1.5 kΩ C = 100 pF) – IN <sub>A</sub> , IN <sub>B</sub> , PWM	2	kV
	– SEL <sub>0</sub>	2	
	– CS	2	
	– V <sub>CC</sub>	4	
	– Output	4	
V <sub>ESD</sub>	Charge device model (CDM-AEC-Q100-011)	750	V
T <sub>c</sub>	Junction operating temperature	-40 to 150	°C
T <sub>STG</sub>	Storage temperature	-55 to 150	°C

## 2.2 Thermal data

Table 5. Thermal data

Symbol	Parameter	Max. value	Unit
R <sub>thj-pin</sub>	Thermal resistance junction-case (per leg) (JEDEC JESD 51-5) <sup>(1)</sup>	TBD	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-ambient (JEDEC JESD 51-5) <sup>(2)</sup>	TBD	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-ambient (JEDEC JESD 51-7) <sup>(1)</sup>	TBD	°C/W

1. Device mounted on four-layers 2s2p PCB.
2. Device mounted on two-layers 2s0p PCB with 2 cm<sup>2</sup> heatsink copper trace.



## 2.3 Electrical characteristics

Values specified in this section are for  $V_{CC} = 7\text{ V}$  up to  $28\text{ V}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ , unless otherwise specified.

**Table 6. Power section**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{CC}$	Operating supply voltage		4		28	V
$I_S$	Supply current	Off-state -standby; $I_{N_A} = I_{N_B} = 0$ ; $SEL_0 = 0$ ; PWM = 0; $T_j = 25^\circ\text{C}$ ; $V_{CC} = 13\text{ V}$			1	$\mu\text{A}$
		Off-state -standby; $I_{N_A} = I_{N_B} = 0$ ; $SEL_0 = 0$ ; PWM = 0; $V_{CC} = 13\text{ V}$ ; $T_j = 85^\circ\text{C}$			1	$\mu\text{A}$
		Off-state -standby; $I_{N_A} = I_{N_B} = 0$ ; $SEL_0 = 0$ ; PWM = 0; $V_{CC} = 13\text{ V}$ ; $T_j = 125^\circ\text{C}$			3	$\mu\text{A}$
		Off-state (no standby); $I_{N_A} = I_{N_B} = 0$ ; $SEL_0 = 5\text{ V}$ ; PWM = 0		2	4	mA
		On-state: $I_{N_A}$ or $I_{N_B} = 5\text{ V}$ ; PWM = 0 V or PWM=5 V; $SEL_0 = X$		3	6	mA
$T_{D\_sdbly}$	Standby mode blanking time	$V_{CC} = 13\text{ V}$ ; $I_{N_A} = I_{N_B} = 0\text{ V}$ ; $V_{SEL0}$ from 5 V to 0 V	0.2	1	1.8	ms
$R_{ONHS}$	Static high-side resistance	$I_{OUT} = 3.5\text{ A}$ ; $T_j = 25^\circ\text{C}$		42		m $\Omega$
		$I_{OUT} = 3.5\text{ A}$ ; $T_j = -40$ to $150^\circ\text{C}$			85	m $\Omega$
$R_{ONLS}$	Static low-side resistance	$I_{OUT} = 3.5\text{ A}$ ; $T_j = 25^\circ\text{C}$		30		m $\Omega$
		$I_{OUT} = 3.5\text{ A}$ ; $T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$			60	m $\Omega$
$V_f$	High-side free-wheeling diode forward voltage	$I_{OUT} = -3.5\text{ A}$ ; $T_j = 150^\circ\text{C}$		0.7	0.9	V
$I_{L(off)}$	Off-state output current of one leg	$I_{N_A} = I_{N_B} = 0$ ; PWM = 0; $V_{CC} = 13\text{ V}$ ; $T_j = 25^\circ\text{C}$	0		0.5	$\mu\text{A}$
		$I_{N_A} = I_{N_B} = 0$ ; PWM = 0; $V_{CC} = 13\text{ V}$ ; $T_j = 125^\circ\text{C}$	0		3	$\mu\text{A}$
$I_{L(off\_h)}$	Off-state output current of one leg with other HSD on	$I_{N_A} = 0$ ; $I_{N_B} = 5\text{ V}$ ; PWM = 0; $V_{CC} = 13\text{ V}$		20	60	$\mu\text{A}$

**Table 7. Logic inputs ( $I_{N_A}$ ,  $I_{N_B}$ ) ( $V_{CC} = 7\text{ V}$  up to  $28\text{ V}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ )**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IL}$	Input low level voltage				0.9	V
$V_{IH}$	Input high level voltage		2.1			V

**Table 7. Logic inputs (IN<sub>A</sub>, IN<sub>B</sub>) (V<sub>CC</sub> = 7 V up to 28 V; -40 °C < T<sub>j</sub> < 150 °C) (continued)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V <sub>IHYST</sub>	Input hysteresis voltage		0.2			V
V <sub>ICL</sub>	Input clamp voltage	I <sub>IN</sub> = 1 mA	5.3		7.2	V
		I <sub>IN</sub> = -1 mA		-0.7		V
I <sub>INL</sub>	Input current	V <sub>IN</sub> = 0.9 V	1			μA
I <sub>INH</sub>	Input current	V <sub>IN</sub> = 2.1 V			10	μA
<b>SEL<sub>0</sub> (V<sub>CC</sub> = 7 V up to 18 V; -40 °C &lt; T<sub>j</sub> &lt; 150 °C)</b>						
V <sub>SELL</sub>	Input low level voltage				0.9	V
I <sub>SELL</sub>	Low level input current	V <sub>SEL</sub> = 0.9 V	1			μA
V <sub>SELH</sub>	Input high level voltage		2.1			V
I <sub>SELH</sub>	High level input current	V <sub>SEL</sub> = 2.1 V			10	μA
V <sub>SEL(hyst)</sub>	Input hysteresis voltage		0.2			V
V <sub>SELCL</sub>	Input clamp voltage	I <sub>SEL</sub> = 1 mA	5.3		7.5	V
		I <sub>SEL</sub> = -1 mA		-0.7		V
<b>PWM (V<sub>CC</sub> = 7 V up to 28 V; -40 °C &lt; T<sub>j</sub> &lt; 150 °C)</b>						
V <sub>PWM</sub>	Input low level voltage				0.9	V
I <sub>PWM</sub>	Low level input current	V <sub>PMW</sub> = 0.9 V	1			μA
V <sub>PWM</sub>	Input high level voltage		2.1			V
I <sub>PWMH</sub>	High level input current	V <sub>PMW</sub> = 2.1 V			10	μA
V <sub>PWM(hyst)</sub>	Input hysteresis voltage		0.2			V
V <sub>PMWCL</sub>	Input clamp voltage	I <sub>PMW</sub> = 1 mA	5.3		7.2	V
		I <sub>PMW</sub> = -1 mA		-0.7		V

**Table 8. Switching (V<sub>CC</sub> = 13 V, R<sub>LOAD</sub> = 3.7 Ω)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
f	PWM frequency		0		20	kHz
t <sub>d(on)</sub>	Turn-on delay time	Input rise time < 1 μs (see <a href="#">Figure 6</a> )		22		μs
t <sub>d(off)</sub>	Turn-off delay time	Input rise time < 1 μs (see <a href="#">Figure 6</a> )		11		μs
t <sub>r</sub>	Rise time	See <a href="#">Figure 5</a>		1	2	μs
t <sub>f</sub>	Fall time	See <a href="#">Figure 5</a>		1	2	μs
t <sub>cross</sub>	Low-side turn-on delay time	Input rise time < 1 μs (see <a href="#">Figure 7</a> )	40	140	240	μs

Table 9. Protections and diagnostics ( $V_{CC} = 7\text{ V}$  up to  $18\text{ V}$ ;  $-40\text{ °C} < T_j < 150\text{ °C}$ )

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{USD}$	Undervoltage shutdown				4	V
$V_{USDreset}$	Undervoltage shutdown reset				5	V
$V_{USDHyst}$	Undervoltage shutdown Hysteresis			0.3		V
$I_{LIM\_H}$	High-side current limitation		15	22	30	A
$I_{SD\_LS}$	Shutdown LS current		18	27	36	A
$t_{SD\_LS}$	Time to shutdown for the low-side	$IN_A = 5\text{ V}$ ; $IN_B = 0\text{ V}$ ; PWM = 5 V (see <a href="#">Figure 8</a> )		5		$\mu\text{s}$
$V_{CL\_HSD}$	High-side clamp voltage ( $V_{CC}$ to $OUT_A = 0$ or $OUT_B = 0$ )	$I_{OUT} = 3.5\text{ A}$ ; $L = 6\text{ mH}$ ; $T_j = -40\text{ °C}$	38			V
		$I_{OUT} = 3.5\text{ A}$ ; $L = 6\text{ mH}$ ; $T_j = 25\text{ °C}$ to $150\text{ °C}$	41	46		V
$V_{CL\_LSD}$	Low-side clamp voltage ( $OUT_A = V_{CC}$ or $OUT_B = V_{CC}$ to GND)	$I_{OUT} = 3.5\text{ A}$ ; $L = 6\text{ mH}$	38	46		V
$T_{TSD\_HS}$	High-side thermal shutdown temperature	$IN_x = 2.1\text{ V}$	150	175	200	$^{\circ}\text{C}$
$T_{TR\_HS}$	High-side thermal reset temperature		135			$^{\circ}\text{C}$
$T_{HYST\_HS}$	High-side thermal hysteresis ( $T_{SD\_HS} - T_{R\_HS}$ )			7		$^{\circ}\text{C}$
$T_{TSD\_LS}$	Low-side thermal shutdown temperature	$IN_x = 0\text{ V}$	150	175	200	$^{\circ}\text{C}$
$V_{CL}$	Total clamp voltage ( $V_{CC}$ to GND)	$I_{OUT} = 3.5\text{ A}$ ; $L = 6\text{ mH}$	38	46	52	V
$V_{OL}$	OFF-state open-load voltage detection threshold	$IN_A = IN_B = 0\text{ V}$ ; PWM = 0; $V_{SEL0} = 5\text{ V}$ for CHA; $V_{SEL0} = 0\text{ V}$ and within $t_{d\_stby}$ for CHB	2	3	4	V
$I_{L(off2)}$	OFF-state output sink current	$IN_A = IN_B = 0$ ; $V_{OUT} = V_{OL}$ ; PWM = 0 V; $V_{SEL0} = 5\text{ V}$ for CHA; $V_{SEL0} = 0\text{ V}$ and within $t_{d\_stby}$ for CHB	-100		-15	$\mu\text{A}$
$t_{DSTKON}$	OFF-state diagnostic delay time from falling edge of INPUT (see <a href="#">Figure 4</a> )	$IN_A = 5\text{ V}$ to $0\text{ V}$ ; $IN_B = 0$ ; $V_{SEL0} = 5\text{ V}$ ; PWM = 0; $I_{OUT} = 0\text{ A}$ ; $V_{OUTA} = 4\text{ V}$	40	140	240	$\mu\text{s}$

Table 9. Protections and diagnostics ( $V_{CC} = 7\text{ V}$  up to  $18\text{ V}$ ;  $-40\text{ }^{\circ}\text{C} < T_j < 150\text{ }^{\circ}\text{C}$ )

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{D\_VOL}$	OFF-state diagnostic delay time from rising edge of $V_{OUT}$	$I_{NA} = I_{NB} = 0\text{ V}$ ; $PWM = 0$ ; $V_{OUTx} = 0\text{ V}$ to $4\text{ V}$ $V_{SELO} = 5\text{ V}$ for CHA; $V_{SELO} = 0\text{ V}$ and within $t_{d\_stby}$ for CHB		5	30	$\mu\text{s}$
$t_{LATCH\_RST\_HS}$	Input reset time for high side fault unlatch <sup>(1)</sup>	$V_{INx} = 5\text{ V}$ to $0\text{ V}$ , HSDx faulting	3	10	20	$\mu\text{s}$
$t_{LATCH\_RST\_LS}$	Input reset time for low side fault unlatch <sup>(1)</sup>	$V_{INx} = 0\text{ V}$ to $5\text{ V}$ , LSDx faulting	3	10	20	$\mu\text{s}$

1. Parameter guaranteed by design and characterization; not subject to production test.

Table 10. CS ( $7\text{ V} < V_{CC} < 18\text{ V}$ )

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{SENSE\_CL}$	Multisense clamp voltage	$V_{SEn} = 0\text{ V}$ ; $I_{SENSE} = -1\text{ mA}$		TBD		
		$V_{SEn} = 0\text{ V}$ ; $I_{SENSE} = 1\text{ mA}$	-17		-12	V
$K_0$	$I_{OUT}/I_{SENSE}$	$I_{OUT} = 0.05\text{ A}$ ; $V_{SENSE} = 0.5\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	665			
$K_1$	$I_{OUT}/I_{SENSE}$	$I_{OUT} = 0.2\text{ A}$ ; $V_{SENSE} = 0.5\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	1140	1900	2660	
$K_2$	$I_{OUT}/I_{SENSE}$	$I_{OUT} = 3.5\text{ A}$ ; $V_{SENSE} = 4\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	1385	1540	1695	
$K_3$	$I_{OUT}/I_{SENSE}$	$I_{OUT} = 6\text{ A}$ ; $V_{SENSE} = 4\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	1415	1540	1665	
$dK_0/K_0^{(1)}$	Analog sense current drift	$I_{OUT} = 0.05\text{ A}$ ; $V_{SENSE} = 0.5\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	-25		25	%
$dK_1/K_1^{(1)}$	Analog sense current drift	$I_{OUT} = 0.2\text{ A}$ ; $V_{SENSE} = 0.5\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	-21		21	%
$dK_2/K_2^{(1)}$	Analog sense current drift	$I_{OUT} = 3.5\text{ A}$ ; $V_{SENSE} = 4\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	-5		5	%
$dK_3/K_3^{(1)}$	Analog sense current drift	$I_{OUT} = 6\text{ A}$ ; $V_{SENSE} = 4\text{ V}$ ; $T_j = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$	-4		4	%
$V_{SENSEsat}$	Max analog sense output voltage	$V_{CC} = 7$ ; $R_{SENSE} = 10\text{ k}\Omega$ ; $V_{SELO} = 5\text{ V}$ $I_{OUT} = 6\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	5			V
$I_{SENSE\_SAT}$	Multisense saturation current	$V_{CC} = 7\text{ V}$ ; $V_{INA} = 5\text{ V}$ ; $V_{INB} = 0\text{ V}$ ; $V_{sel0} = 5\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	4			mA
$I_{OUT\_SAT}^{(2)}$	Output saturation current	$V_{CC} = 7\text{ V}$ ; $V_{SENSE} = 4\text{ V}$ ; $V_{INA} = 5\text{ V}$ ; $V_{INB} = 0\text{ V}$ ; $V_{sel0} = 5\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	6			A

Table 10. CS (7 V < V<sub>CC</sub> < 18 V) (continued)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V <sub>out_MSD</sub> <sup>(2)</sup>	Output Voltage for Multisense Shut-Down	V <sub>INA</sub> = 5 V; V <sub>INB</sub> = 0 V; V <sub>SEL0</sub> = 5 V; V <sub>SEL1</sub> = 0 V; R <sub>SENSE</sub> = 2.7 kΩ; I <sub>OUT</sub> = 3.5 A		5		V
I <sub>SENSE0</sub>	CS leakage current	I <sub>OUT</sub> = 0 A; V <sub>SENSE</sub> = 0 V; I <sub>N<sub>x</sub></sub> = 0 V; SEL <sub>0</sub> = 0 T <sub>j</sub> = -40°C to 150°C (Standby)	0		0.5	μA
		I <sub>OUT</sub> = 0 A; V <sub>SENSE</sub> = 0 V; I <sub>N<sub>x</sub></sub> = 0 V; SEL <sub>0</sub> = 5 V; T <sub>j</sub> = -40°C to 150°C (No Standby)	0		0.5	μA
		I <sub>N<sub>x</sub></sub> = 5 V; PWM = 5 V; I <sub>OUT</sub> = 0 A; T <sub>j</sub> = -40°C to 150°C	0		5	μA
V <sub>SENSEH</sub>	CS output voltage in fault condition	V <sub>CC</sub> = 13 V; R <sub>SENSE</sub> = 1 kΩ – E.g: Ch <sub>0</sub> in open-load V <sub>IN</sub> = 0 V; I <sub>OUT</sub> = 0 A; V <sub>OUT</sub> = 4 V	5		7	V
I <sub>SENSEH</sub>	CS output voltage in fault condition	V <sub>CC</sub> = 13 V; V <sub>SENSE</sub> = V <sub>SENSEH</sub>	7	20	30	mA

1. Analog sense current drift is deviation of factor K for a given device over (-40 °C to 150 °C and 9 V < V<sub>CC</sub> < 18 V) with respect to its value measured at T<sub>j</sub> = 25 °C, V<sub>CC</sub> = 13 V.
2. Parameter guaranteed by design and characterization; not subject to production test.

Figure 4. T<sub>DSTKON</sub>

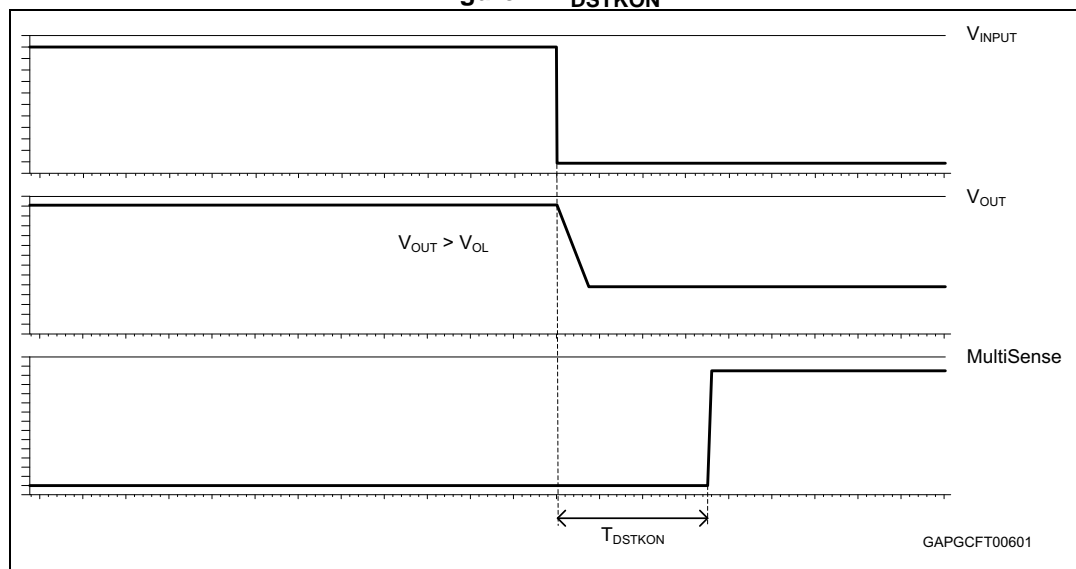


Figure 5. Definition of the low-side switching times

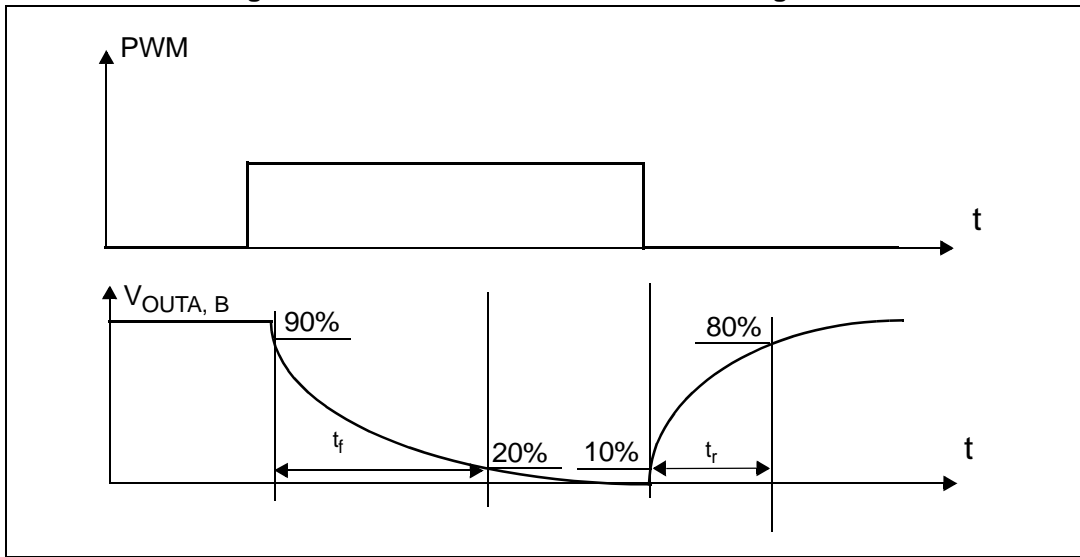


Figure 6. Definition of the high-side switching times

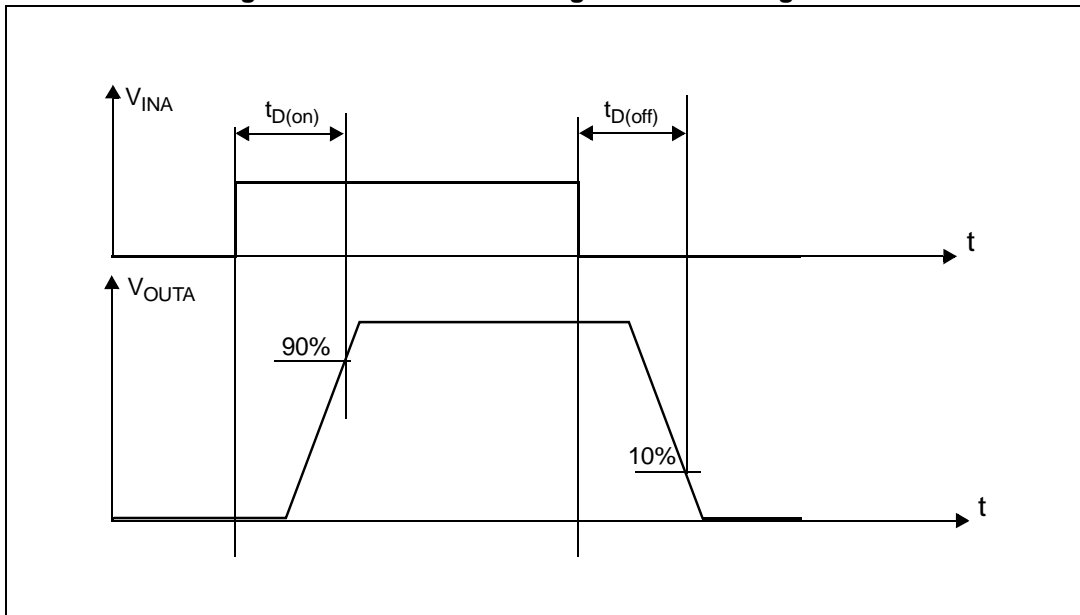


Figure 7. Low-side turn-on delay time

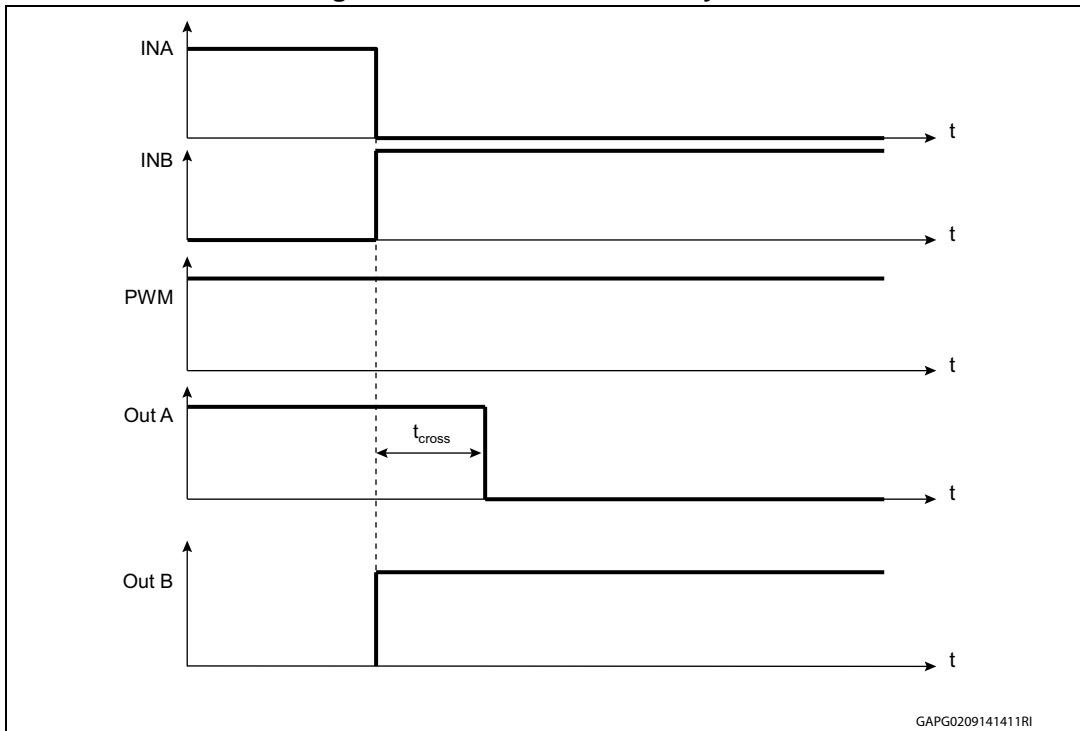


Figure 8. Time to shutdown for the low-side driver

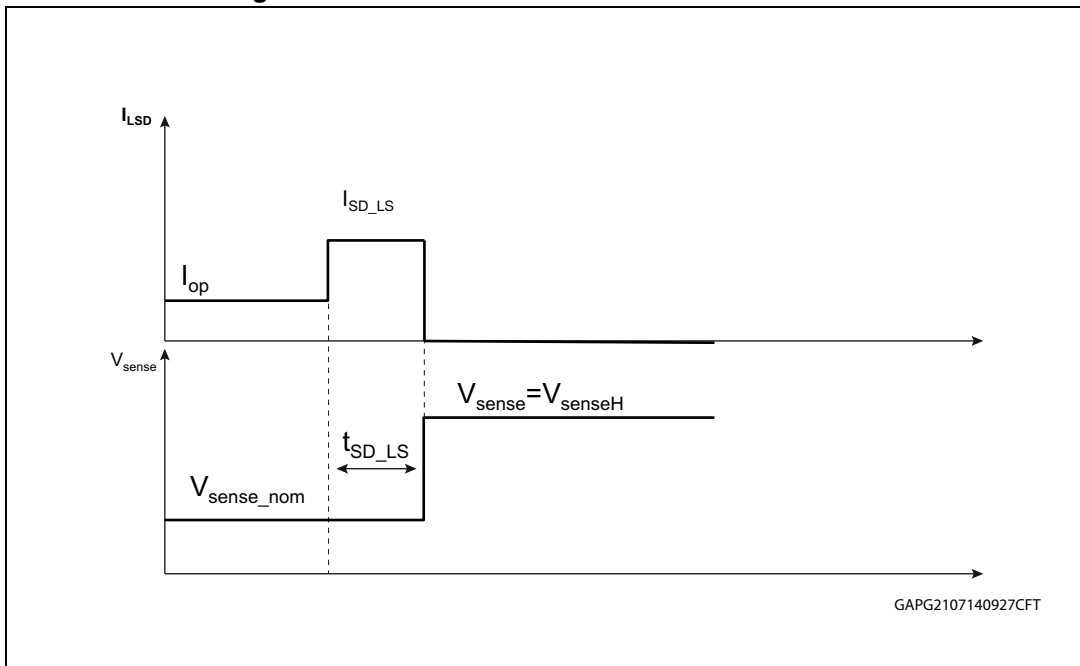


Table 11. Operative condition - truth table

Pin status					HSDs and LDSs Statu			
IN <sub>A</sub>	IN <sub>B</sub>	SEL <sub>0</sub>	PWM	CS	HSDA	LSDA	HSDB	LSDB
1	1	1	x	Current Monitoring HSDA	On	Off	On	Off
		0		Current Monitoring HSDB				
1	0	1	1	Current Monitoring HSDA	On	Off	Off	On
			0		On	Off	Off	Off
1	0	0	1	Hi-Z	On	Off	Off	On
			0		On	Off	Off	Off
0	1	1	1	Hi-Z	Off	On	On	Off
			0		Off	Off	On	Off
0	1	0	1	Current Monitoring HSDB	Off	On	On	Off
			0		Off	Off	On	Off
0	0	1	1	Hi-Z	Off	On	Off	On
		0						
0	0	1	0	x <sup>(1)</sup>	Off	Off	Off	Off
		0 <sup>(2)</sup>						

1. Refer to [Table 13: Off-state -truth table](#)
2. For IN<sub>A</sub> = IN<sub>B</sub> = SEL<sub>0</sub> = PWM = 0, the device enters in standby after T<sub>D\_sdbdy</sub>

Table 12. On-state fault conditions- truth table Fault on leg A (preliminary)

IN <sub>A</sub>	IN <sub>B</sub>	SEL <sub>0</sub>	PWM	Out <sub>A</sub>	Out <sub>B</sub>	CS	Fault description
On state diagnostic							
1	0	1	X	L	L	V <sub>SENSEH</sub>	Out A short to GND
1	0	0	1	H	H	V <sub>SENSEH</sub>	Out B short to V <sub>CC</sub>
0	1	1	1	H	H	V <sub>SENSEH</sub>	Out A short to V <sub>CC</sub>
0	1	0	X	X	L	V <sub>SENSEH</sub>	Out B short to GND





Table 13. Off-state -truth table

IN <sub>A</sub>	IN <sub>B</sub>	SEL <sub>0</sub>	PWM	Out <sub>A</sub>	Out <sub>B</sub>	CS	Description
Off-state diagnostic							
0	0	1	0	$V_{outA} > V_{OL}$	x	$V_{SENSEH}$	Case 1. Out <sub>A</sub> shorted to V <sub>CC</sub> if no pull-up is applied Case 2. No open-load in full bridge configuration with an external pull-up on Out <sub>B</sub> Case 3. open-load in half bridge configuration with an external pull-up on Out <sub>A</sub> (motor connected between Out <sub>A</sub> and Ground)
				$V_{outA} < V_{OL}$	x	Hi-Z	Case 1. Open-load in full Bridge configuration with an external pull-up on Out <sub>B</sub> Case 2. No open-load in half Bridge configuration with external pull-up on Out <sub>A</sub> (motor connected between Out <sub>A</sub> and Ground)
		0 <sup>(1)</sup>		x	$V_{outB} > V_{OL}$	$V_{SENSEH}$	Case 1. Out <sub>B</sub> shorted to V <sub>CC</sub> if no pull-up is applied Case 2. No open-load in full bridge configuration with external pull-up on Out <sub>A</sub> Case 3. Open-load in half bridge configuration with external pull-up on Out <sub>B</sub> (motor connected between Out <sub>B</sub> and Ground)
				x	$V_{outB} < V_{OL}$	Hi-Z	Case1. Open-load in full Bridge configuration with an external pull-up on Out <sub>A</sub> Case 2. No open-load in half Bridge configuration with external pull-up on Out <sub>B</sub> (motor connected between Out <sub>B</sub> and Ground)

1. The device enters standby mode after T<sub>D\_sdb</sub>y

## 3 Application information

### 3.1 GND protection network against reverse battery

#### 3.1.1 Diode ( $D_{GND}$ ) in the ground line

A resistor (typ.  $R_{GND} = 4.7 \text{ k}\Omega$ ) should be inserted in parallel to  $D_{GND}$  if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network produces a shift ( $\approx 600 \text{ mV}$ ) in the input threshold and in the status output values if the microprocessor ground is not common to the device ground. This shift does not vary if more than one HSD shares the same diode/resistor network.

### 3.2 Immunity against transient electrical disturbances

The immunity of the device against transient electrical emissions, conducted along the supply lines and injected into the  $V_{CC}$  pin, is tested in accordance with ISO7637-2:2011 (E) and ISO 16750-2:2010.

The related function performance status classification is shown in [Table 14](#).

Test pulses are applied directly to DUT (Device Under Test) both in ON and OFF-state and in accordance to ISO 7637-2:2011(E), chapter 4. The DUT is intended as the present device only, without components and accessed through  $V_{CC}$  and GND terminals.

Status II is defined in ISO 7637-1 Function Performance Status Classification (FPSC) as follows: "The function does not perform as designed during the test but returns automatically to normal operation after the test".

**Table 14. ISO 7637-2 - electrical transient conduction along supply line**

Test Pulse 2011(E)	Test pulse severity level with Status II functional performance status		Minimum number of pulses or test time	Burst cycle / pulse repetition time		Pulse duration and pulse generator internal impedance
	Level	$U_S^{(1)}$		min	max	
1	III	-112 V	500 pulses	0,5 s		2ms, 10 $\Omega$
2a	III	+55 V	500 pulses	0,2 s	5 s	50 $\mu$ s, 2 $\Omega$
3a	IV	-220 V	1h	90 ms	100 ms	0.1 $\mu$ s, 50 $\Omega$
3b	IV	+150 V	1h	90 ms	100 ms	0.1 $\mu$ s, 50 $\Omega$
4 <sup>(2)</sup>	IV	-7 V	1 pulse			100ms, 0.0 1 $\Omega$
<b>Load dump according to ISO 16750-2:2010</b>						
Test B <sup>(3)</sup>		40 V	5 pulse	1 min		400 ms, 2 $\Omega$

1.  $U_S$  is the peak amplitude as defined for each test pulse in ISO 7637-2:2011(E), chapter 5.6.
2. Test pulse from ISO 7637-2:2004(E).
3. With 40 V external suppressor referred to ground (-40°C <  $T_j$  < 150°C).

## 4 Package and packing information

### 4.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).

ECOPACK® is an ST trademark.

### 4.2 SO-16N mechanical data

Figure 9. SO-16N package dimensions

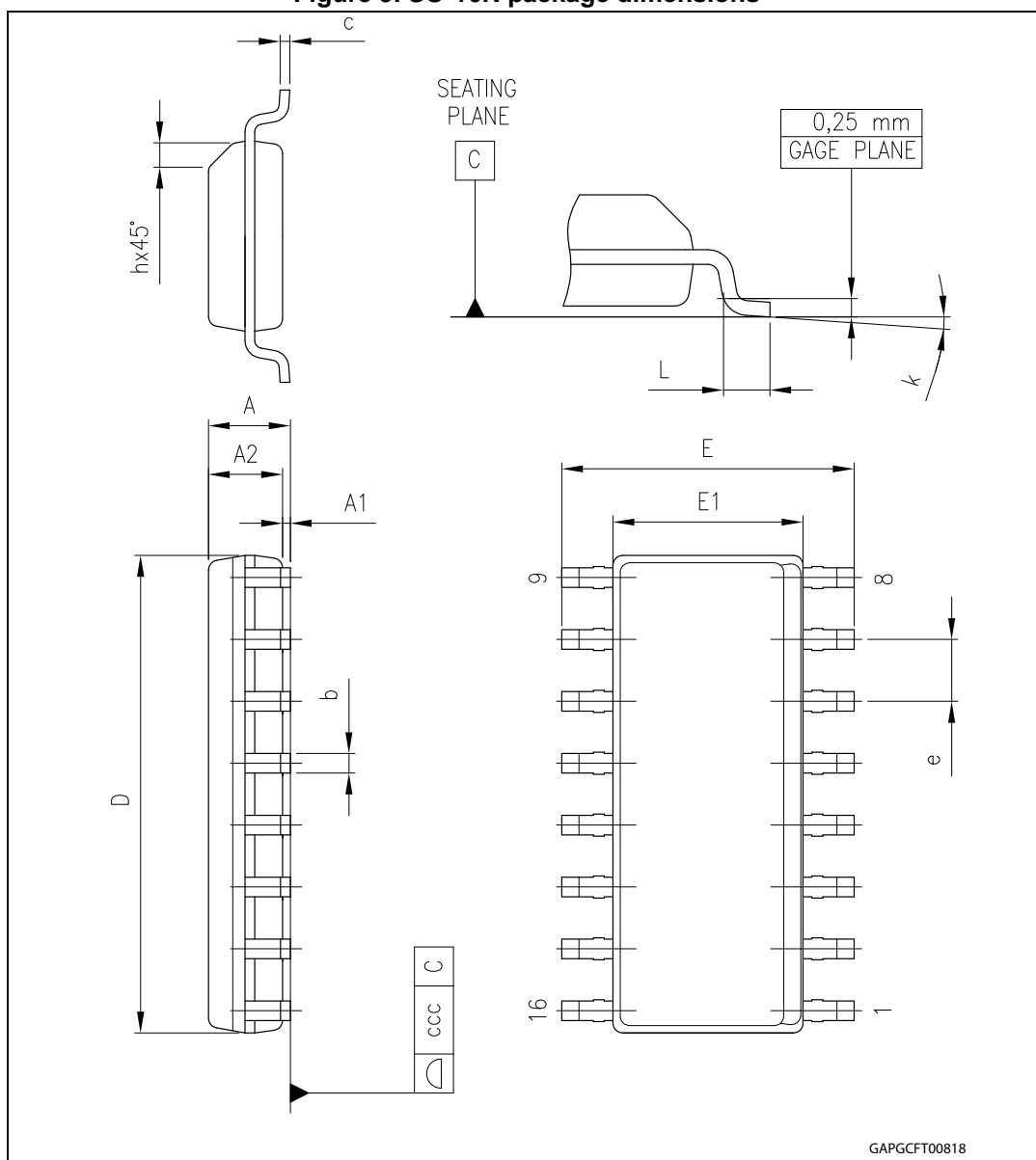


Table 15. SO-16N mechanical data

Symbol	Millimeters		
	Min.	Typ.	Max.
A			1.75
A1	0.10		0.25
A2	1.25		
b	0.31		0.51
c	0.17		0.25
D	9.80	9.90	10.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e		1.27	
h	0.25		0.50
L	0.40		1.27
k	0		8
ccc			1.10

## 5 Revision history

**Table 16. Document revision history**

Date	Revision	Changes
06-Sep-2013	1	Initial release.
13-Sep-2013	2	Changed MultiSense pin in CS.
24-Sep-2013	3	Updated disclaimer.
18-Jun-2014	4	<p><i>Table 4: Absolute maximum ratings:</i></p> <ul style="list-style-type: none"> <li>– <math>I_R</math>: updated value</li> <li>– <math>V_{ESD}</math>: updated parameter</li> </ul> <p><i>Table 6: Power section:</i></p> <ul style="list-style-type: none"> <li>– <math>I_S</math>, <math>R_{ONHS}</math>: updated values</li> <li>– <math>T_{D\_stby}</math>, <math>I_{L(off)}</math>: updated test conditions</li> <li>– <math>I_{L(off\_h)}</math>: updated test conditions</li> </ul> <p><i>Table 8: Switching (VCC = 13 V, RLOAD = 3.7 Ω):</i></p> <ul style="list-style-type: none"> <li>– <math>SEL_0</math>: updated test conditions</li> </ul> <p><i>Table 8: Switching (VCC = 13 V, RLOAD = 3.7 Ω):</i></p> <ul style="list-style-type: none"> <li>– <math>t_{d(on)}</math>, <math>t_{d(off)}</math>: updated values</li> <li>– <math>t_{cross}</math>: added row</li> </ul> <p><i>Table 9: Protections and diagnostics (VCC = 7 V up to 18 V; -40 °C &lt; Tj &lt; 150 °C):</i></p> <ul style="list-style-type: none"> <li>– <math>t_{SD\_LS}</math>: updated value and test conditions</li> <li>– Renamed parameter <math>V_{CLPHsd}</math> into <math>V_{CL\_HSD}</math>, <math>V_{CLPLSD}</math> into <math>V_{CL\_LSD}</math> and <math>V_{CLP}</math> into <math>V_{CL}</math>; updated test conditions and values</li> <li>– <math>V_{OL}</math>, <math>I_{L(off2)}</math>, <math>t_{DSTKON}</math>, <math>t_{D\_VOL}</math>: updated test conditions</li> </ul> <p>Updated <i>Table 10: CS (7 V &lt; VCC &lt; 18 V)</i></p>
10-Oct-2014	5	<p><i>Table 4: Absolute maximum ratings:</i></p> <ul style="list-style-type: none"> <li>– <math>V_{ESD}</math>: updated parameter</li> </ul> <p><i>Table 9: Protections and diagnostics (VCC = 7 V up to 18 V; -40 °C &lt; Tj &lt; 150 °C):</i></p> <ul style="list-style-type: none"> <li>– <math>t_{LATCH\_RST\_HS}</math>, <math>t_{LATCH\_RST\_HS}</math>: added parameters</li> </ul> <p>Changed <i>Figure 7: Low-side turn-on delay time</i> and <i>Figure 8: Time to shutdown for the low-side driver</i></p>
24-Nov-2014	6	<p>Updated:</p> <ul style="list-style-type: none"> <li>– <i>Table 7: Logic inputs (INA, INB) (VCC = 7 V up to 28 V; -40 °C &lt; Tj &lt; 150 °C)</i></li> <li>– <i>Table 9: Protections and diagnostics (VCC = 7 V up to 18 V; -40 °C &lt; Tj &lt; 150 °C)</i></li> <li>– <i>Table 10: CS (7 V &lt; VCC &lt; 18 V)</i></li> <li>– <i>Figure 8: Time to shutdown for the low-side driver</i></li> </ul>

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